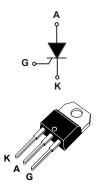


High temperature 30 A, 600 V TO220 insulated thyristor SCRs



TO-220AB insulated

Features

- High junction temperature: T_j = 150 °C
- High noise immunity dV/dt = 1000 V/µs up to 150 °C
- Peak off-state voltage V_{DRM}/V_{RRM} = 600 V
- High turn-on current rise dI/dt = 100 A/μs
- ECOPACK2 compliant
- Insulated package TO-220AB:
 - Insulated voltage: 2500 V_{RMS}
 - Complies with UL 1557 (File ref : E81734)

Applications

- · General purpose AC line load switching
- · Motorbike voltage regulator circuits
- · Inrush current limiting circuits
- · Motor control circuits and starters
- · Heating resistor control, Solid State Relays
- Lighting

Description

Thanks to its operating junction temperature up to 150°C, the TN3015H-6I offers high thermal performance operation up to 30 A rms.

Its trade-off noise immunity (dV/dt = 1000 V/ μ s) versus its gate triggering current (I_{GT} = 15 mA) and its turn-on current rise (dI/dt = 100 A/ μ s) allows to design robust and compact control circuit for voltage regulator in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances and inrush current limiting circuits.

Product status	
TN3015H-6I	

Product summary				
Order code	TN3015H-6I			
Package	TO-220AB Ins.			
V_{DRM}/V_{RRM}	600 V			
Tj	150 °C			
I _{GT}	15 mA			



1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter			Value	Unit
I _{T(RMS)}	RMS on-state current (180 ° conduction angle	S on-state current (180 ° conduction angle)		30	Α
			T _c = 96 °C	19	
$I_{T(AV)}$	I _{T(AV)} Average on-state current (180 ° conduction angle) T _c = 111 °C		T _c = 111 °C	15	Α
		$T_{\rm C}$ = 127 °C		10	
I _{TSM}	Non repetitive surge peak on-state current (T	initial = 25 °C\	t _p = 8.3 ms	295	^
ITSM	Non repetitive surge peak on-state current (1	j II III (al = 25 °C)	t _p = 10 ms	270	Α
l ² t	I ² t value for fusing (T _j initial = 25 °C)		t _p = 10 ms	364	A ² s
dl/dt	I _G = 2 x I _{GT} , tr ≤ 100 ns	f = 60 Hz	T _i = 25 °C	100	A/µs
di/dt	Critical rate of rise of on-state current	1 = 60 HZ	1j - 25 C	100	ΑνμS
V_{DRM}/V_{RRM}	Repetitive peak off-state voltage			600	V
$V_{\rm DSM}/V_{\rm RSM}$	Non repetitive surge peak off-state voltage	t _p = 10 ms	T _j = 25 °C	$V_{DRM}/V_{RRM} + 100$	V
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	Α
P _{G(AV)}	Average gate power dissipation		T _j = 150 °C	1	W
V_{RGM}	Maximum peak reverse gate voltage		T _j = 25 °C	5	V
T _{stg}	Storage junction temperature range			-40 to +150	°C
Tj	Maximum operating junction temperature		-40 to +150	°C	
T _I	Maximum lead temperature soldering during 10 s			260	°C
V _{ins}	Insulation RMS voltage, 1 minute			2500	V

Table 2. Electrical characteristics (T_j = 25 °C unless otherwise specified)

Symbol	Test conditions			Value	Unit
1			Min.	6	mA
I _{GT}	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Max.	15	ША
V _{GT}			Max.	1.3	V
V _{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$		Min.	0.15	V
I _H	I _T = 500 mA, gate open Max			60	mA
IL	$I_G = 1.2 \times I_{GT}$		Max.	75	mA
dV/dt	V_D = 402 V, gate open T_j = 150 °C		Min.	1000	V/µs
t _{gt}	$I_T = 60 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA}, (dI_G/dt) \text{ max} = 0.2 \text{ A/}\mu\text{s}$ Typ.		1.9	μs	
tq	I_T = 30 A, V_D = 402 V,(di/dt)off = 30 A/µs, V_R = 25 V, dV_D/dt = 50 V/µs T_j = 150 °C		Тур.	80	μs

DS12967 - Rev 1 page 2/10



Table 3. Static characteristics

Symbol	Test conditions			Value	Unit
V _{TM}	$I_{TM} = 60 \text{ A}, t_p = 380 \mu\text{s}$	T _j = 25 °C	Max.	1.6	V
V _{TO}	Threshold voltage	T _j = 150 °C	Max.	0.84	V
R _D	Dynamic resistance	T _j = 150 °C	Max.	14	mΩ
I _{DRM} , I _{RRM}	$V_D = V_{DRM}$, $V_R = V_{RRM}$	T _j = 25 °C	Max.	10	μA
	VD - VDRM, VR - VRRM	T _j = 150 °C	iviax.	5	mA

Table 4. Thermal parameters

Symbol	Parameter	Value	Unit	
R _{th(j-c)}	Junction to case	Max.	1.9	°C/W
R _{th(j-a)}	Junction to ambient	Тур.	60	C/VV

DS12967 - Rev 1 page 3/10



1.1 Characteristics curves

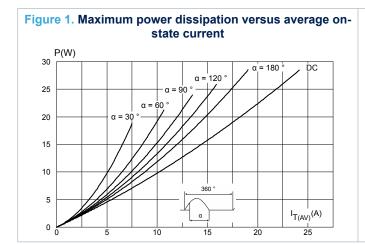
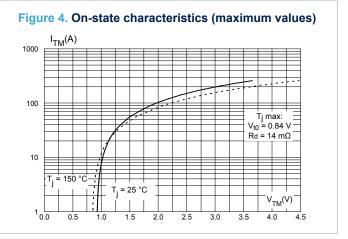
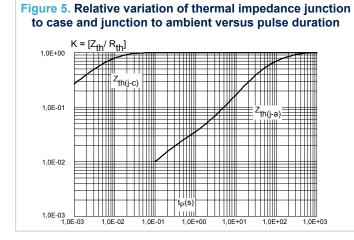
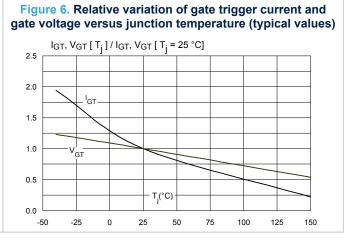


Figure 3. Average and D.C. on state current versus ambient temperature







DS12967 - Rev 1 page 4/10



Figure 7. Relative variation of holding and latching current versus junction temperature (typical values)

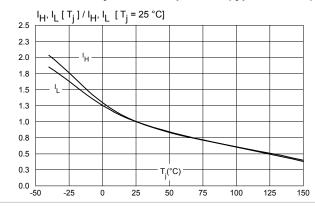


Figure 8. Relative variation of static dV/dt immunity versus junction temperature (typical values)

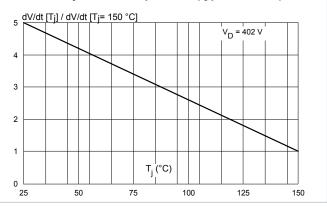


Figure 9. Surge peak on-state current versus number of cycles

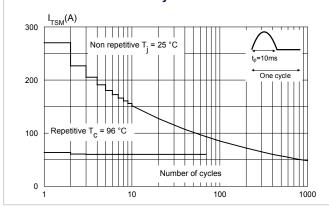


Figure 10. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms

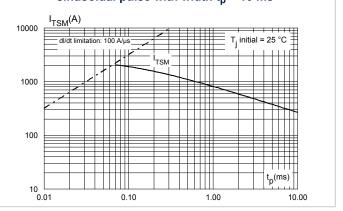
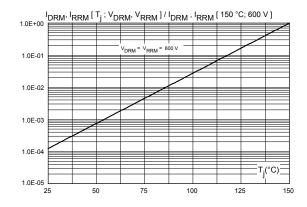


Figure 11. Relative variation of leakage current versus junction temperature



DS12967 - Rev 1 page 5/10



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TO-220AB insulated package information

- Molding compound resin is halogen-free and meets flammability standard UL94 level 0
- · Lead-free package leads finishing
- ECOPACK2 compliant
- Recommended torque: 0.4 to 0.6 N.m

В b2 Resin gate 0.5 mm max. protusion⁽¹⁾ F Α 14 13 c2 a1 12 a2 M c1 Resin gate 0.5 mm b1 max. protusion(1)

Figure 12. TO-220AB insulated package outline

(1)Resin gate position accepted in one of the two positions or in the symmetrical opposites.

DS12967 - Rev 1 page 6/10



Table 5. TO-220AB insulated package mechanical data

Dimensions						
Ref.	Millimeters			Inches ⁽¹⁾		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
В	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
С	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
е	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
12	1.14		1.70	0.0449		0.0669
13	1.14		1.70	0.0449		0.0669
14	15.80	16.40	16.80	0.6220	0.6457	0.6614
М		2.6			0.1024	

^{1.} Inch dimensions are for reference only.

DS12967 - Rev 1 page 7/10



3 Ordering information

Figure 13. Ordering information scheme

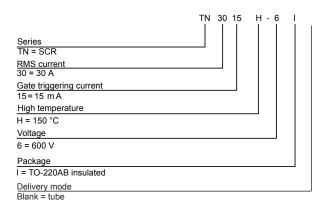


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN3015H-6I	TN3015H6I	TO-220AB ins.	2.3 g	50	Tube

DS12967 - Rev 1 page 8/10



Revision history

Table 7. Document revision history

Date	Revision	Changes
22-May-2019	1	Initial release.

DS12967 - Rev 1 page 9/10



IMPORTANT NOTICE - PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, please refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2019 STMicroelectronics - All rights reserved

DS12967 - Rev 1 page 10/10